

Description

The UMW IRS2304STR is a high voltage, high speed power MOSFET drivers with dependent high- and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The IRS2304STR is integrated with a bootstrap diode to charge the high side, simplifying the peripheral circuit of the chip. The floating channel can be used to drive an N-channel power MOSFET in the high-side configuration which operates up to 700 V.

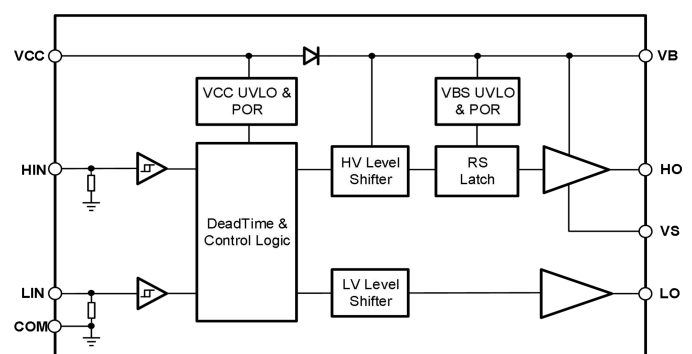
Application

- Motor Control
- Air Conditioners/ Washing Machines
- General Purpose Inverters
- Micro/Mini Inverter Drives

Features and Benefits

- Floating channel designed for bootstrap operation
- Fully operational to +700 V
- 3.3V, 5V and 15V input logic compatible
- Tolerant to negative transient voltage, dV/dt immune
- Allowable negative Vs capability: -9V
- Gate drive supply range from 10V to 20V
- Matched propagation delay for both channels
- Wide operating temperature range -40°C ~125°C
- Cross-conduction prevention
- Internal 100ns deadtime
- Typically output Source/Sink current capability: 300mA/600mA

Functional Block Diagram



Function Pin Description

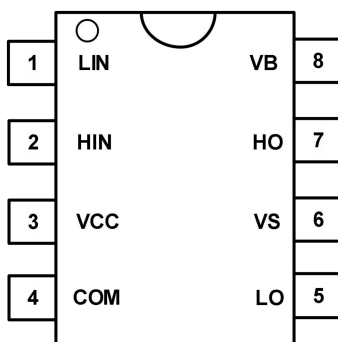


Figure7-1 8-Pin SOIC8 Top view

Table7-1 Lead Definitions

Number	Symbol	Description
1	LIN	Logic input for low side gate driver output (LO), in phase
2	HIN	Logic input for high side gate driver output (HO), in phase
3	VCC	Low side and logic fixed supply
4	COM	Low side return
5	LO	Low side gate drive output
6	VS	High side floating supply return
7	HO	High side gate drive output
8	VB	High side floating supply

Absolute Maximum Ratings

Exceeding the limit maximum rating may cause permanent damage to the device. All voltage parameters are rated with reference to COM and an ambient temperature of 25°C.

Symbol	Definition	MIN.	MAX.	Units
V _B	High side floating supply	-0.3	725	V
V _S	High side floating supply return	V _B - 25	V _B + 0.3	
V _{HO}	High side gate drive output	V _S -0.3	V _B + 0.3	
V _{CC}	Low side and main power supply	-0.3	25	
V _{LO}	Low side gate drive output	-0.3	V _{CC} + 0.3	
V _{IN}	Logic input of HIN & LIN	-0.3	V _{CC} + 0.3	
dV _S /dt	Allowable Offset Supply Voltage Transient	—	50	V/ns
ESD	HBM Model	1500	—	V
	Machine Model	500	—	V
P _D	Package Power Dissipation @ TA ≤25°C	—	625	mW
R _{thJA}	Thermal Resistance, Junction to Ambient	--	200	°C/W
T _J	Junction Temperature	—	150	
T _S	Storage Temperature	-55	150	°C
T _L	Lead Temperature (Soldering, 10 seconds)	—	300	°C/W

Recommended Operating Conditions

For proper operation, the device should be used under the following recommended conditions. The bias ratings of VS and COM are measured at a supply voltage of 15V, and unless otherwise specified, the ratings of all voltage parameters are referenced to COM and the ambient temperature is 25°C.

Symbol	Definition	MIN.	MAX.	Units
V _B	High side floating supply	V _S + 10	V _S + 20	V
V _S	High side floating supply return	-9	700	
V _{HO}	High side gate drive output	V _S	V _B	
V _{CC}	Low side and main power supply	10	20	
V _{LO}	Low side gate drive output	0	V _{CC}	
V _{IN}	Logic input of HIN & LIN	0	V _{CC}	
T _A	Ambient temperature	-40	125	°C

Note1: Transient negative VS can be used for COM-50V with a pulse width of 50ns, guaranteed by design..

Note2: When the input pulse width is less than 1us, the input pulse cannot be transmitted normally .

Electrical Characteristics

Valid for temperature range at $T_A = 25^\circ\text{C}$, $V_{CC} = V_B = 15\text{V}$, $C_L = 1\text{nF}$, unless otherwise specified

Symbol	Definition	MIN.	TYP.	MAX.	Units	Test Condition
t_{ON}	Turn-on propagation delay	—	130	200	ns	$V_S = 0\text{V}$
t_{OFF}	Turn-off propagation delay	—	130	200	ns	$V_S = 700\text{V}$
t_R	Turn-on rise time	—	75	130	ns	
t_F	Turn-off fall time	—	35	70	ns	
DT	Deadtime	80	100	190	ns	
MT	Matched propagation time delay	—	—	50	ns	
MDT	Matched deadtime delay	—	—	60	ns	

Static electrical characteristics

Valid for temperature range at $T_A = 25^\circ\text{C}$, $V_{CC} = V_B = 15\text{V}$, $C_L = 1\text{nF}$, unless otherwise specified.

Symbol	Definition	MIN.	TYP.	MAX.	Units	Test Condition
V_{CCUV+} V_{BSUV+}	VCC and VBS supply UVLO threshold	8	8.9	9.8	V	
V_{CCUV-} V_{BSUV-}		7.4	8.2	9.0	V	
$V_{CCUVHYS}$ $V_{BSUVHYS}$	hysteresis of V_{CC} and V_{BS} UVLO	—	0.7	—	V	
I_{LK}	High-side floating supply leakage current	—	—	50	μA	$V_B = V_S = 700\text{V}$
I_{QBS}	Quiescent VB supply current	—	50	100	μA	$V_{IN} = 0\text{V}$ or 5V
I_{QCC}	Quiescent VCC supply current	—	120	240	μA	$V_{IN} = 0\text{V}$ or 5V
V_{IH}	Logic “1” (HIN&LIN) input voltage	2.5	—	—	V	$V_{CC} = 10\text{V}$ to 20V
V_{IL}	Logic “0” (HIN&LIN) input voltage	—	—	0.8	V	$V_{CC} = 10\text{V}$ to 20V
V_{OH}	High level output voltage, $V_{BIAS} - V_O$	—	—	0.1	V	$I_O = 0\text{A}$
V_{OL}	Low level output voltage, V_O	—	—	0.1	V	$I_O = 0\text{A}$
I_{IN+}	Logic “1” Input bias current	—	5	10	μA	$I_N = 5\text{V}$
I_{IN-}	Logic “0” Input bias current	—	—	2	μA	$I_N = 0\text{V}$
I_{O+}	Output high short circuit pulsed current	200	300	—	mA	$V_O = 0\text{V}$ $PW \leq 10\mu\text{s}$
I_{O-}	Output low short circuit pulsed current	400	600	—	mA	$V_O = 15\text{V}$ $PW \leq 10\mu\text{s}$
V_{BSD}	Bootstrap diode conduction voltage		0.6		V	$I_{BSD} = 1\text{mA}$
R_{BSD}	Bootstrap diode conduction resistance		200		Ω	$I_{BSD} = 10\text{mA}$

Function Description

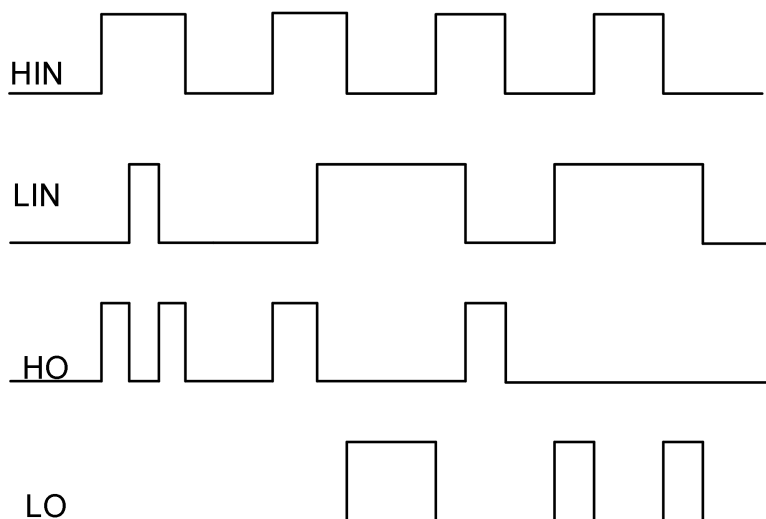


Figure 5. IRS2304STR Input and output timing waveform

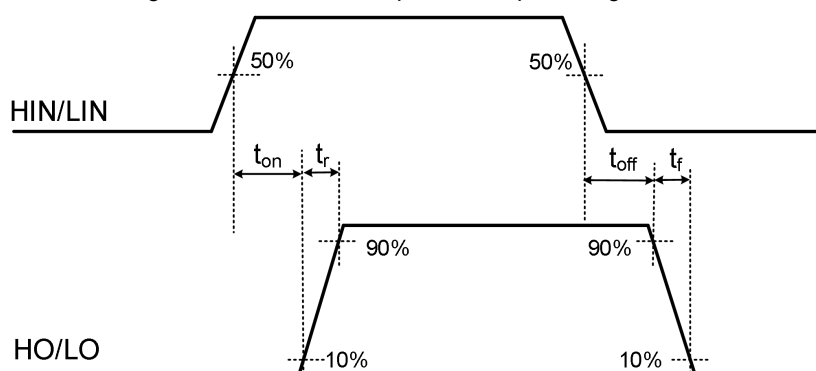


Figure 6. Propagation Time Waveform Definition

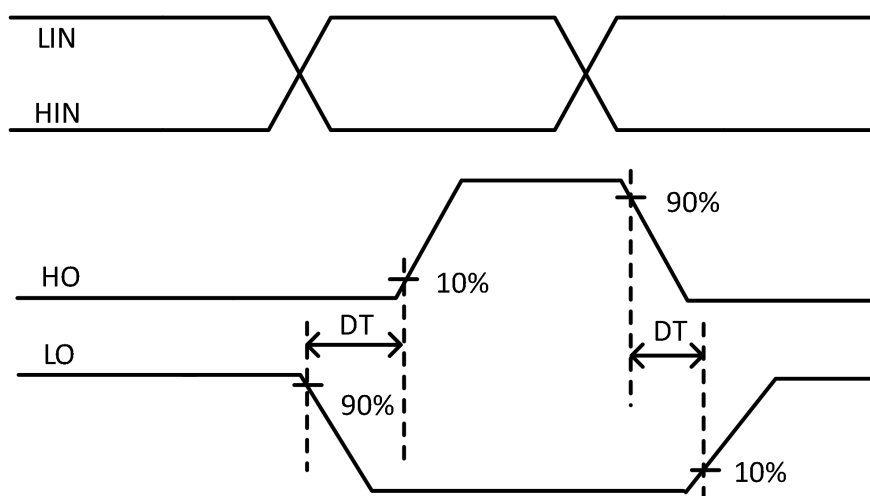


Figure 7. Cross Conduction Prevention Delay Time Waveform Definition

Function Block Diagram

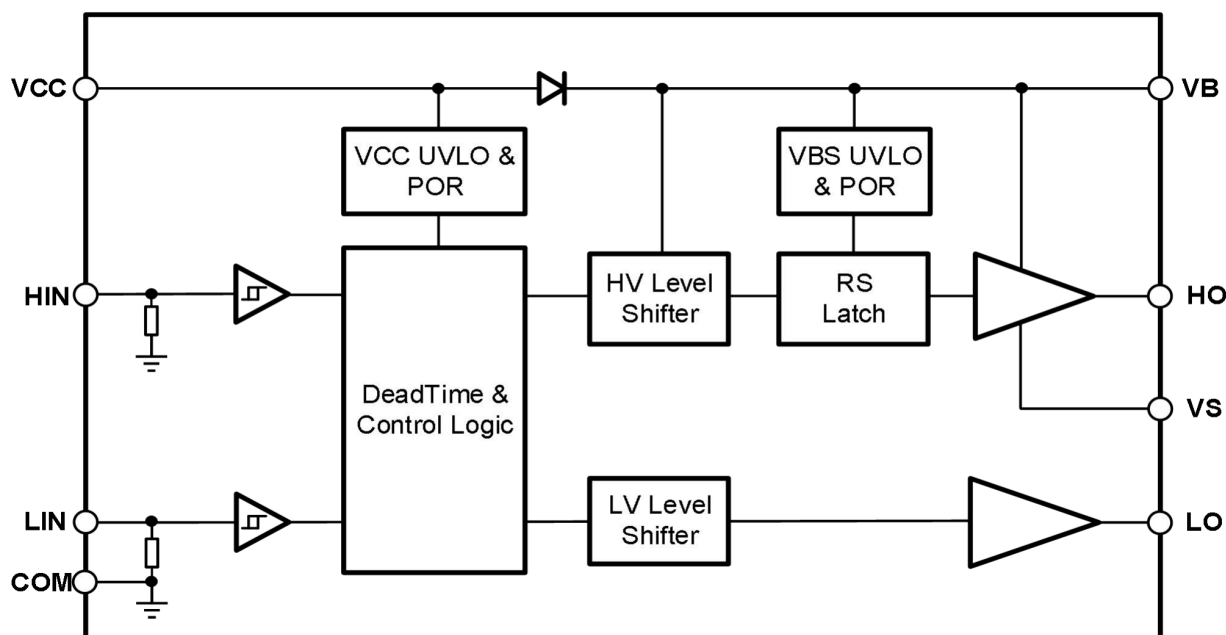


Figure10-1 Function Block Diagram of IRS2304STR

Application message

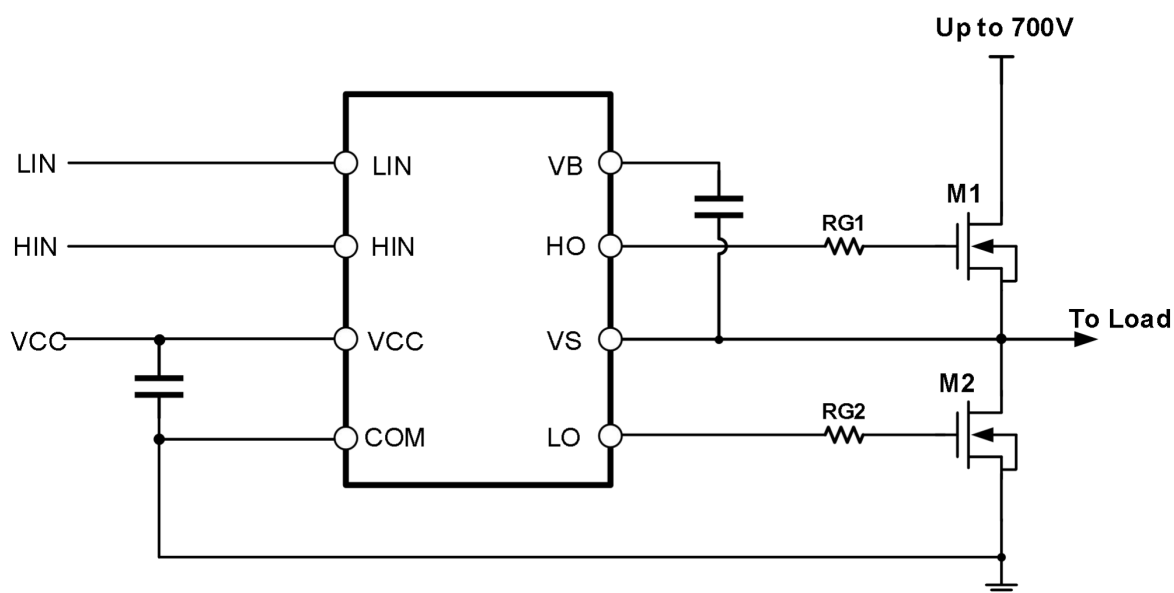
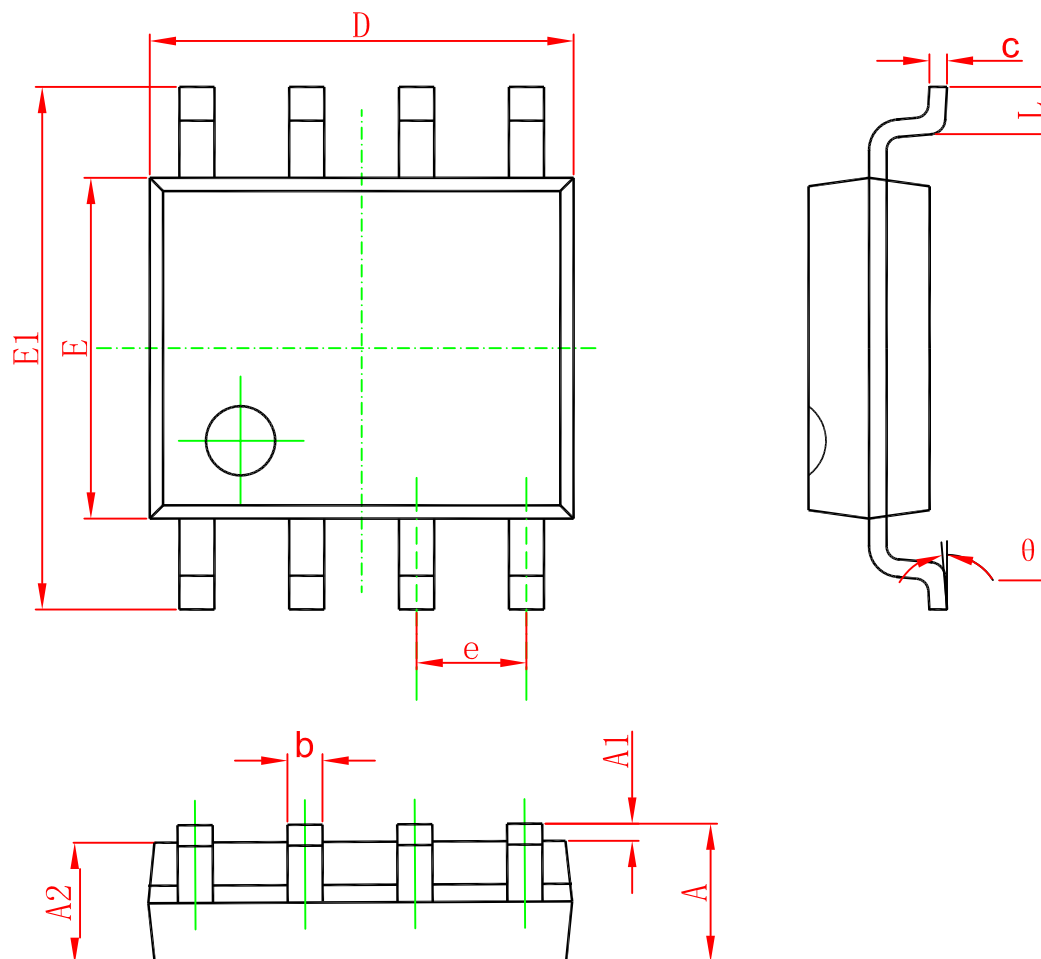


Figure10-2 Typical application circuit of IRS2304STR

PACKAGING INFORMATION

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Marking

Ordering information

Order code	Package	Baseqty	Deliverymode
UMW IRS2304STR	SOP-8	2500	Tape and reel

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